2SC5413

Silicon NPN triple diffusion mesa type

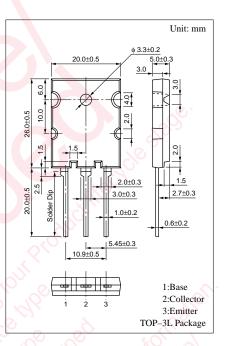
For horizontal deflection output

Features

- High breakdown voltage, and high reliability through the use of a glass passivation layer
- High-speed switching
- Wide area of safe operation (ASO)

	in Raings	$(1_{C}-25C)$	
Parameter	Symbol	Ratings	Unit
Collector to base voltage	V _{CBO}	1700	V
Collector to amittan voltage	V _{CES}	1700	V
Collector to emitter voltage	V _{CEO}	600	V
Emitter to base voltage	V _{EBO}	5	V
Peak collector current	I _{CP}	30	A
Collector current	I _C	20	A
Base current	I _B	10	A
Collector power $T_C=25^{\circ}C$	D	200	W
dissipation Ta=25°C	P _C	3.5	XC'W. XC
Junction temperature	Tj	150	C)
Storage temperature	T _{stg}	-55 to +150	°C v

Absolute Maximum Ratings (T_c=25°C)



Electrical Characteristics (T_c=25°C)

Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	I _{CBO}	$V_{CB} = 1000V, I_E = 0$	·O.		50	μΑ
		$V_{CB} = 1700V, I_E = 0$			1	mA
Emitter cutoff current	I _{EBO}	$V_{EB} = 5V, I_C = 0$			50	μΑ
Forward current transfer ratio	h _{FE}	$V_{CE} = 5V, I_C = 10A$	7		14	
Collector to emitter saturation voltage	V _{CE(sat)}	$I_{\rm C} = 10$ A, $I_{\rm B} = 2.8$ A			3	V
Base to emitter saturation voltage	V _{BE(sat)}	$I_{\rm C} = 10$ A, $I_{\rm B} = 2.8$ A			1.5	V
Transition frequency	f _T	$V_{CE} = 10V, I_C = 0.1A, f = 0.5MHz$		3		MHz
Storage time	t _{stg}				4.0	μs
Fall time	t _f	$I_{\rm C} = 12$ A, $I_{\rm B1} = 2.4$ A, $I_{\rm B2} = -4.8$ A			0.3	μs

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